imall

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P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	Ι _D T _C = +25°C
-40V	9.9mΩ @ V _{GS} = -10V	-50A
-40 v	14mΩ @ V _{GS} = -4.5V	-45A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- **DC-DC Converters**
- **Power Management Functions**
- Backlighting

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

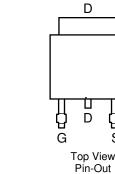
Mechanical Data

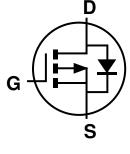
- Case: TO252
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (9)
- Weight: 0.33 grams (Approximate)



TO252

Top View





Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP4010SK3-13	TO252	2,500/Tape & Reel

S

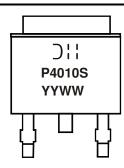
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/guality/lead free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free. "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



⊃!! = Manufacturer's Marking P4010S = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 15 = 2015) WW = Week (01 to 53)



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-40	V
Gate-Source Voltage			V _{GSS}	±25	V
St St		$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	ID	-50 -40	А
Continuous Drain Current (Note 6) $V_{GS} = -10V$	Steady State	T _A = +25°C T _A = +70°C	ID	-15 -12	А
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	-100	A
Maximum Body Diode Forward Current (Note 6)			Is	-5.5	A
Avalanche Current, L = 1mH (Note 7)			I _{AS}	-22	A
Avalanche Energy, L = 1mH (Note 7)			E _{AS}	260	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	73	°C/W
Total Power Dissipation (Note 6)		PD	3.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	38	°C/W
Thermal Resistance, Junction to Case		R _{eJC}	1.0	-0/00
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)				•			
Drain-Source Breakdown Voltage	BV _{DSS}	-40	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}			-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		—	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1.5	-2	-2.5	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance			7.5	9.9	mΩ	$V_{GS} = -10V, I_D = -9.8A$	
Static Drain-Source On-nesistance	R _{DS(ON)}		10.5	14	11152	$V_{GS} = -4.5V, I_D = -9.8A$	
Diode Forward Voltage	V _{SD}		-0.7	-1	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss		4,234	—			
Output Capacitance	Coss		1,036	—	pF	$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Reverse Transfer Capacitance	C _{rss}		526	_			
Gate Resistance	Rg		7.8	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Qg		42.7	_			
Total Gate Charge (V _{GS} = -10V)	Qg		91	_	nC	$\begin{array}{l} V_{DS}=-20V,\\ I_{D}=-9.8A \end{array}$	
Gate-Source Charge	Q _{gs}	_	14.2	_	no		
Gate-Drain Charge	Q _{gd}	_	13.5	_			
Turn-On Delay Time	t _{D(ON)}	_	13.2	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_G = 6\Omega, I_D = -1A$	
Turn-On Rise Time	t _R		10				
Turn-Off Delay Time	tD(OFF)	_	303	_	ns		
Turn-Off Fall Time	t _F	_	138	_			
Reverse Recovery Time	t _{RR}	_	26	—	ns	I _F = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Q _{RR}		20	_	nC	I _F = -9.8A, di/dt = -100A/μs	

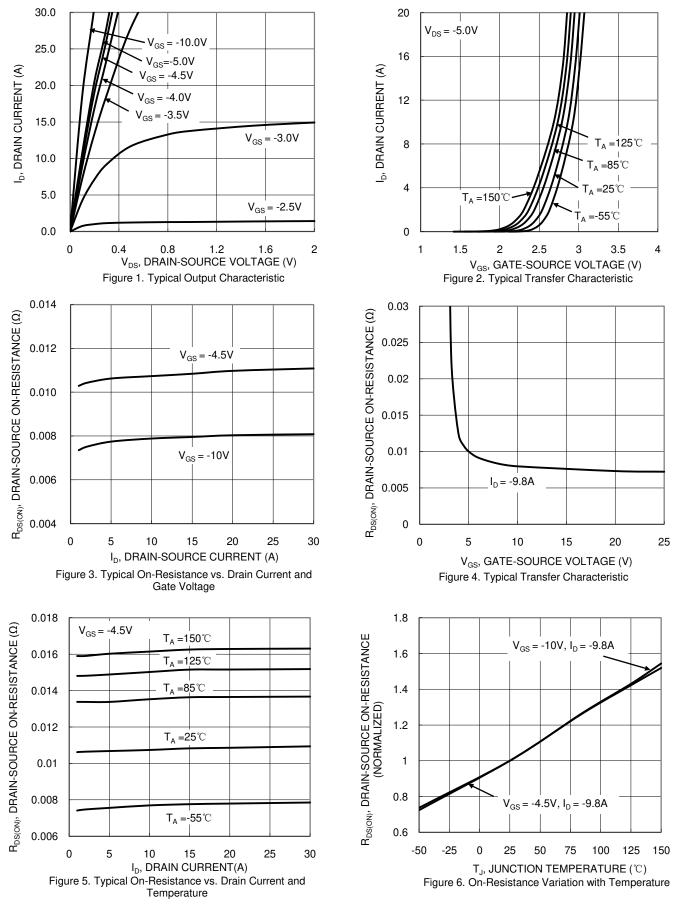
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. IAS and EAS ratings are based on low frequency and duty cycles to keep T_J = +25°C.

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.



DMP4010SK3



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DMP4010SK3

100 125 150

 $I_D = -1mA$

50

75

 C_{iss}

 C_{oss}

15

20

=10us

=100ms

H

, 1111

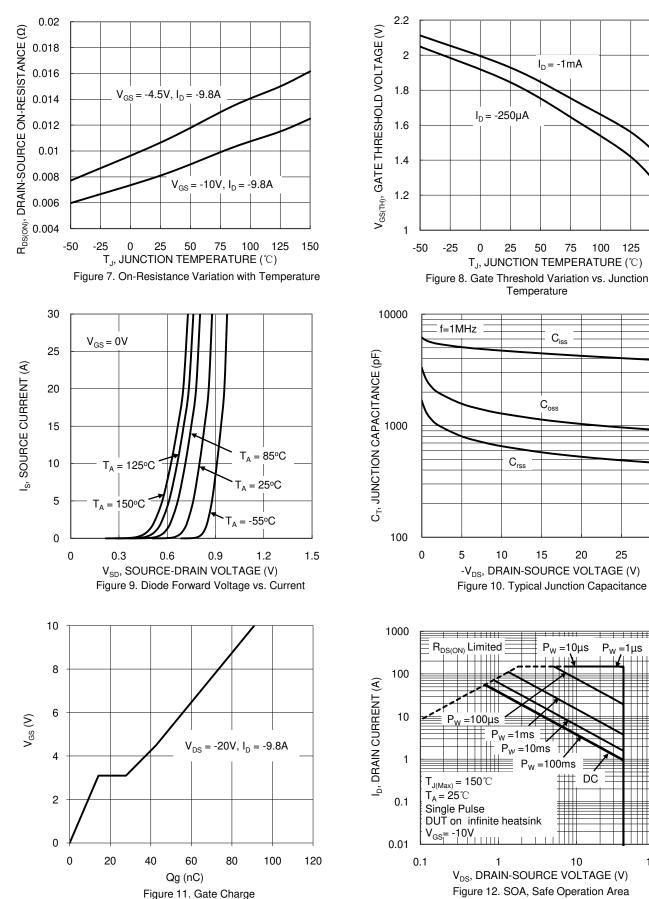
10

DĊ

25

1us

30



NEW PRODUCT

DMP4010SK3 Document number: DS37770 Rev. 2 - 2 100



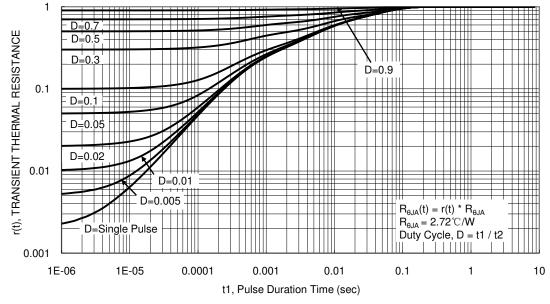
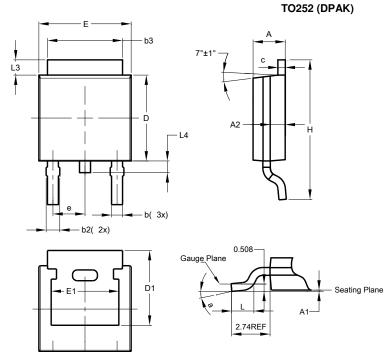


Figure 13. Transient Thermal Resistance



Package Outline Dimensions

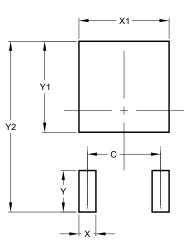
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



TO252 (DPAK)				
Dim	Min	Max	Тур	
Α	2.19	2.39	2.29	
A1	0.00	0.13	0.08	
A2	0.97	1.17	1.07	
b	0.64	0.88	0.783	
b2	0.76	1.14	0.95	
b3	5.21	5.46	5.33	
С	0.45	0.58	0.531	
D	6.00	6.20	6.10	
D1	5.21			
е	_	_	2.286	
Е	6.45	6.70	6.58	
E1	4.32	_	_	
Н	9.40	10.41	9.91	
L	1.40	1.78	1.59	
L3	0.88	1.27	1.08	
L4	0.64	1.02	0.83	
а	0°	10°	_	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



FO252	(DPAK)

Dimensions	Value (in mm)
С	4.572
Х	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

1	
2	



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